



1200V N-Channel Silicon Carbide Power MOSFET

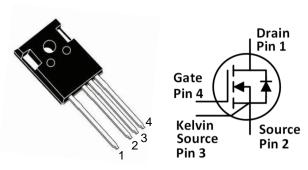
Features:

- High blocking voltage with low on-resistance
- High speed switching with low capacitance
- High operating junction temperature capability
- Very fast and robust intrinsic body diode
- Kelvin gate input easing driver circuit design

Applications:

- Solar inverters
- UPS
- Motor drivers
- High voltage DC/DC converters
- Switch mode power supplies

Package:



Top View

Part Number	Package
DTN58N120SC4	TO247-4

Absolute Maximum Ratings (Tc=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{DS}	Drain-Source voltage	1200	V	V _{GS} =0V, I _D =100μA	
V_{GS}	Gate-Source voltage	-5 to 20	V	Recommended maximum	
I _D	Drain current (continuous)	58	А	V _{GS} =20V, T _C =25°C	Eig. 21
ID		43	Α	V _{GS} =20V, T _C =100°C	Fig. 21
I _{DM}	Drain current (pulsed)	145	А	Pulse width limited by SOA	Fig. 24
Ртот	Total power dissipation	344	W	T _C =25°C	Fig. 22
T_{stg}	Storage temperature range	-55 to 175	°C		
Tı	Operating junction temperature	-55 to 175	°C		
	Solder Temperature	260	°C	Wave soldering only allowed	
Tι				at leads, 1.6mm from case	
				for 10 s	

Thermal Data

Symbol Parameter		Value	Unit	Note	
$R_{\theta(J-C)}$	Thermal Resistance from Junction to Case	0.436	°C/W	Fig. 23	

1



Electrical Characteristics (Tc=25°C unless otherwise specified)

Symbol	Parameter	Value			Unit	Test Conditions	Note
-		Min.	Тур.	Max.			
I _{DSS}	Zero gate voltage drain current		5	100	μΑ	V _{DS} =1200V, V _{GS} =0V	
Igss	Gate leakage current		1	<u>+</u> 100	nA	V _{DS} =0V, V _{GS} =-5~20V	
	Gate threshold voltage		3.2		V	V _{GS} =V _{DS} , I _D =6mA	
V_{TH}			2.2			V _{GS} =V _{DS} , I _D =6mA @ T _C =175°C	Fig. 8, 9
ב	Static drain-source on- resistance		50	65	mΩ	V _{GS} =20V, I _D =20A @T _J =25°C V _{GS} =20V, I _D =20A @T _J =175°C	Fig. 4, 5, 6, 7
Ron			80		mΩ		
Ciss	Input capacitance		2750		рF		Fig. 16
Coss	Output capacitance		106		рF	\/ -000\/ \/ -0\/	
Crss	Reverse transfer capacitance		5.2		рF	V _{DS} =800V, V _{GS} =0V, f=1MHz, V _{AC} =25mV	
Eoss	Coss stored energy		43		μЈ	-	Fig. 17
Qg	Total gate charge		120		nC	\/ -000\/ I -20A	Fig. 18
Qgs	Gate-source charge		25		nC	V_{DS} =800V, I_{D} =20A, V_{GS} =-5 to 20V	
Q_{gd}	Gate-drain charge		48		nC	V _{GS} =-3 tO 20V	
R_{g}	Gate input resistance		2.8		Ω	f=1MHz	
Eon	Turn-on switching energy		455.4		μЈ		
Eoff	Turn-off switching energy		213.6		μJ	$V_{DS} = 800V$, $I_{D} = 30A$, $V_{GS} = -2$ to 20V, $R_{G(ext)} = 3.3\Omega$,	Fig. 19, 20
t _{d(on)}	Turn-on delay time		8.9				
t r	Rise time		28.9		nc		
$t_{\text{d(off)}}$	Turn-off delay time		25.6		ns	L=450μH	
t_{f}	Fall time		17.2				

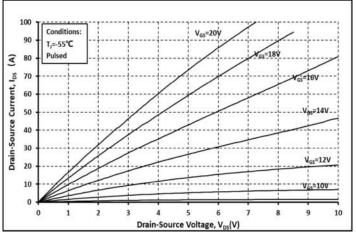


Reverse Diode Characteristics (Tc=25°C unless otherwise specified)

Symbol	Parameter	Value			Unit	Test Conditions	Note
		Min.	Тур.	Max.			
	Diode forward voltage		4.9		V	I _{SD} =20A, V _{GS} =0V	Fig. 10, 11, 12
V_{SD}			4.4		V	I _{SD} =20A, V _{GS} =0V, T _J =175°C	
trr	Reverse recovery time		44.4		ns	V _{GS} =-2V/+20V,	
Qrr	Reverse recovery charge		212.6		nC	I _{SD} =30A, V _R =800V, di/dt=1000A/us,	
I _{RRM}	Peak reverse recovery current		10.8		А	$R_{G(ext)}=10\Omega$ L=450 μ H	



Typical Performance (curves)



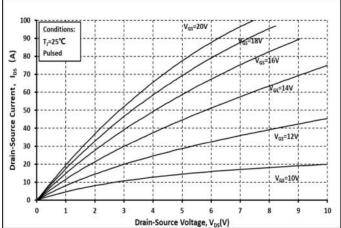
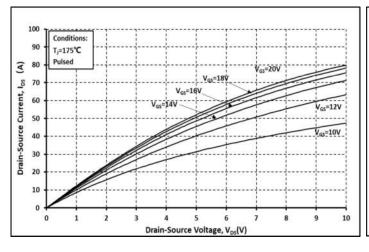


Fig. 1 Output Curve @ T₁=-55°C

Fig. 2 Output Curve @ T₁=25°C



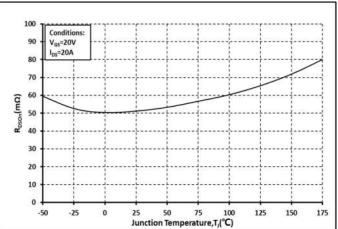
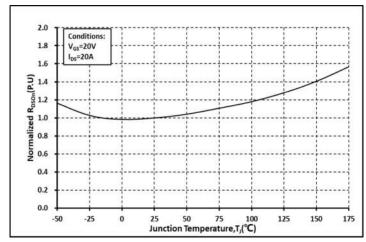


Fig. 3 Output Curve @ T,=175°C

Fig. 4 Ron vs. Temperature



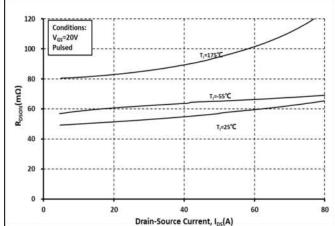
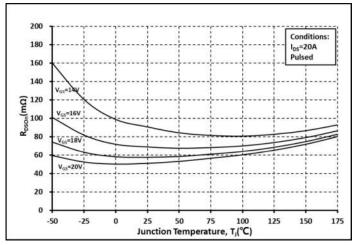


Fig. 5 Normalized Ron vs. Temperature

Fig. 6 Ron vs. IDS @ Various Temperature



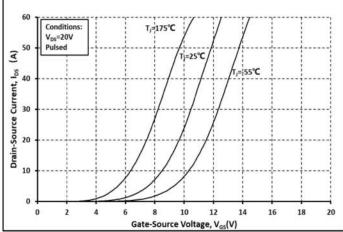
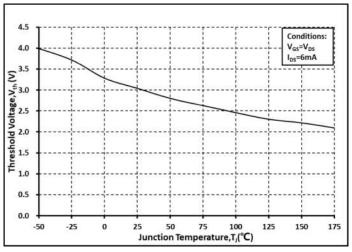


Fig. 7 Ron vs. Temperature @ Various V_{GS}

Fig. 8 Transfer Curves @ Various Temperature



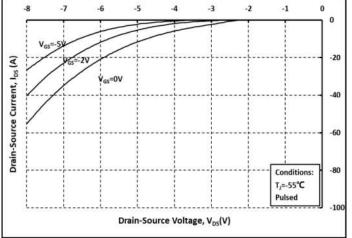
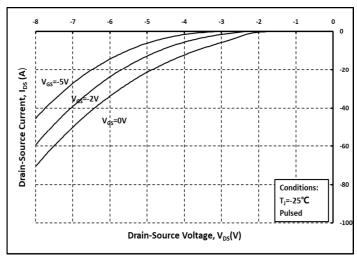


Fig. 9 Threshold Voltage vs. Temperature

Fig. 10 Body Diode Curves @ T₁=-55°C



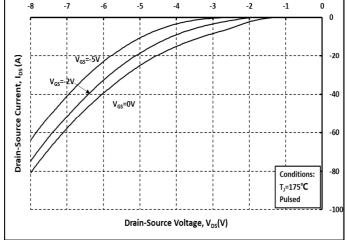
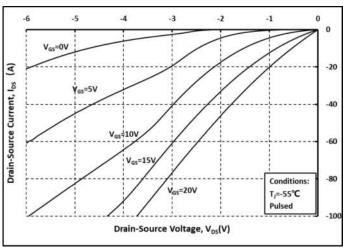


Fig. 11 Body Diode Curves @ T₁=25°C

Fig. 12 Body Diode Curves @ T₁=175°C





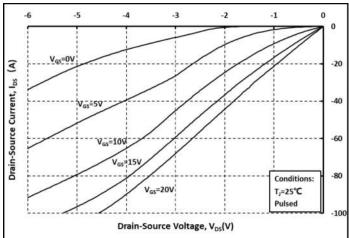
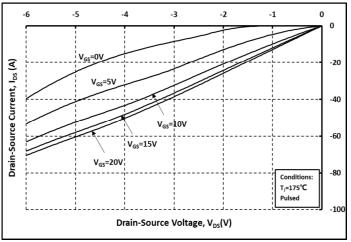


Fig. 13 3rd Quadrant Curves @ T_J=-55°C

Fig. 14 3rd Quadrant Curves @ T_J=25°C



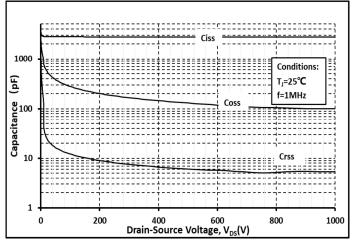
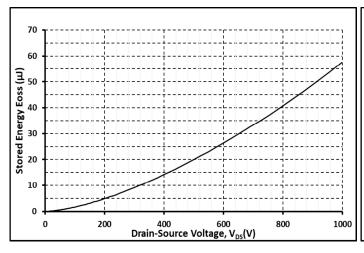


Fig. 15 3rd Quadrant Curves @ T_J=175°C

Fig. 16 Capacitance vs. V_{DS}



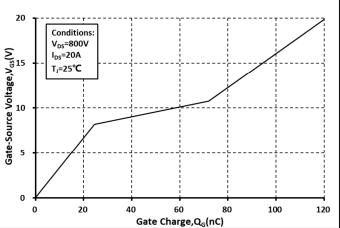
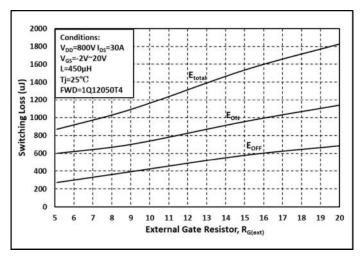


Fig. 17 Output Capacitor Stored Energy

Fig. 18 Gate Charge Characteristics



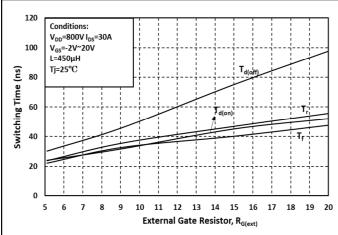
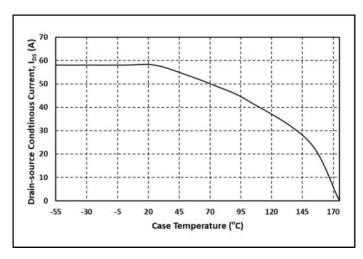


Fig. 19 Switching Energy vs. R_{G(ext)}

Fig. 20 Switching Times vs. R_{G(ext)}



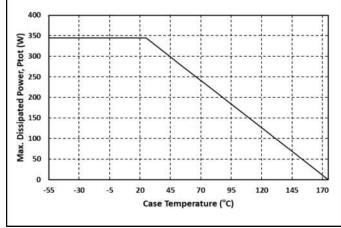
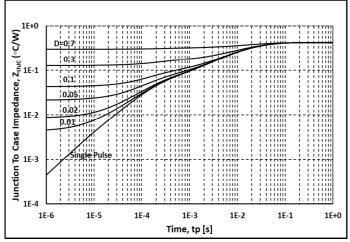


Fig. 21 Continuous Drain Current vs.

Case Temperature

Fig. 22 Max. Power Dissipation Derating vs.

Case Temperature



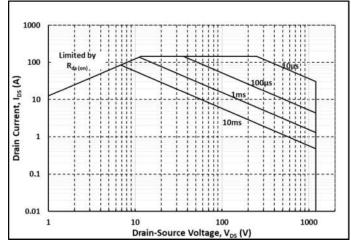


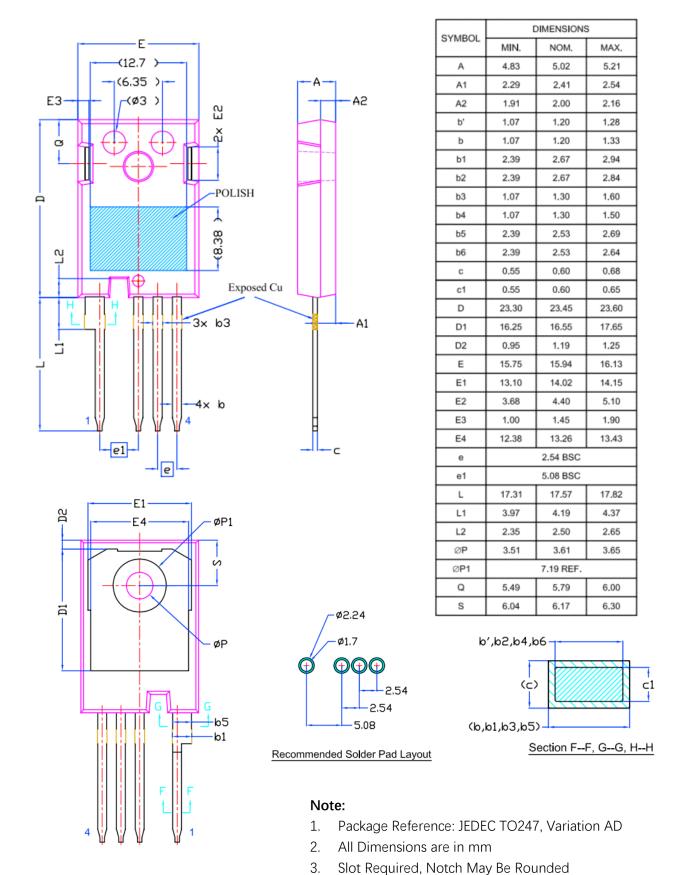
Fig. 23 Thermal Impedance

Fig. 24 Safe Operating Area





Package Dimensions



Dimension D&E Do Not Include Mold Flash

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Din-Tek Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Din-Tek"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Din-Tek makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Din-Tek disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Din-Tek's knowledge of typical requirements that are often placed on Din-Tek products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Din-Tek's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Din-Tek products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Din-Tek product could result in personal injury or death. Customers using or selling Din-Tek products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Din-Tek personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Din-Tek. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Din-Tek Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Din-Tek documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Din-Tek Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Din-Tek documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.